## 2SD2136

### Silicon NPN triple diffusion planar type

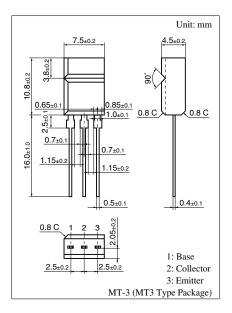
# For power amplification Complementary to 2SB1416

#### ■ Features

- High forward current transfer ratio h<sub>FE</sub> which has satisfactory linearity
- ullet Low collector to emitter saturation voltage  $V_{CE(sat)}$
- Allowing supply with the radial taping

#### ■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit
Collector to base voltage	V <sub>CBO</sub>	60	V
Collector to emitter voltage	V <sub>CEO</sub>	60	V
Emitter to base voltage	V <sub>EBO</sub>	6	V
Peak collector current	$I_{CP}$	5	A
Collector current	$I_{C}$	3	A
Collector power dissipation	$P_{C}$	1.5	W
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C



#### ■ Electrical Characteristics $T_C = 25$ °C

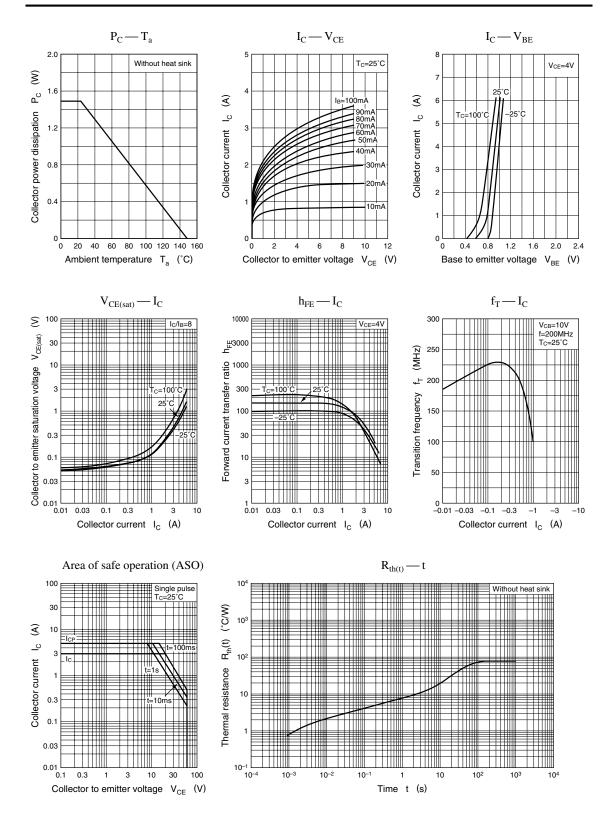
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	I <sub>CES</sub>	$V_{CE} = 60 \text{ V}, V_{BE} = 0$			200	μΑ
	I <sub>CEO</sub>	$V_{CE} = 60 \text{ V}, I_{B} = 0$			300	μΑ
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 6 \text{ V}, I_{C} = 0$			1	mA
Collector to emitter voltage	$V_{CEO}$	$I_C = 30 \text{ mA}, I_B = 0$	60			V
Forward current transfer ratio	h <sub>FE1</sub> *	$V_{CE} = 4 \text{ V}, I_C = 1 \text{ A}$	40		250	
	h <sub>FE2</sub>	$V_{CE} = 4 \text{ V}, I_{C} = 3 \text{ A}$	10			
Base to emitter voltage	$V_{BE}$	$V_{CE} = 4 \text{ V}, I_{C} = 3 \text{ A}$			1.8	V
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 3 \text{ A}, I_B = 0.375 \text{ A}$			1.2	V
Transition frequency	$f_T$	$V_{CE} = 5 \text{ V}, I_{E} = -0.1 \text{ A}, f = 200 \text{ MHz}$		220		MHz
Turn-on time	t <sub>on</sub>	$I_C = 1 \text{ A}, I_{B1} = 0.1 \text{ A}, I_{B2} = -0.1 \text{ A}$		0.5		μs
Storage time	t <sub>stg</sub>			2.5		μs
Fall time	$t_{\mathrm{f}}$			0.4		μs

Note) \*: Rank classification

Rank	Р	Q	R
h <sub>FE1</sub>	40 to 90	70 to 150	120 to 250

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2SD2136 Power Transistors



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